

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Attorney Docket Number	23-69853-01
Application Number	10/727,062
Filing Date	December 2, 2003
First Named Inventor	John G. DeSteele
Art Unit	3744
Examiner Name	Not yet assigned

U.S. PATENT DOCUMENTS

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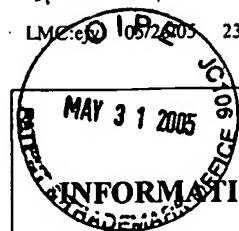
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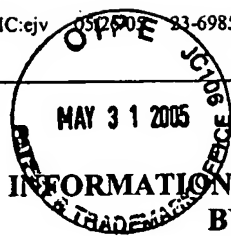
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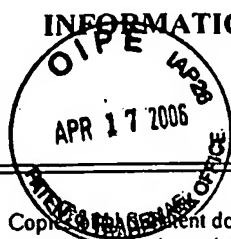
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